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	STATEMENT BY APP	PLIC	CANT	Application Number	10/529,369		
				Filing Date	October 5, 2005		
	May 29, 2009			First Named Inventor	H. MATSUTANI		
				Art Unit	1796		
(use as many sheets as necessary)				Examiner Name	Marc S. Zimmer		
Sheet	1	of	1	Attorney Docket Number	1303,44954X00		

U.S. PATENT DOCUMENTS						
Examiner Initials'	Cite No. ¹	Document Number Number-Kind Code ² (if known)		Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
		US-	Π			
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Examiner Initials'	Cite No.1	Foreign Patent Document Country Code ³ -Number ⁴ -Kind Code ⁵ (# known)	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear	T ⁰
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NON PATENT LITERATURE DOCUMENTS				
Examine r Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the titlem (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.				
/M.Z./		Japanese Official Action dated May 12, 2009, for Japanese Application No. 2003-317572.		
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Examiner Signature	/Marc Zimmer/	Date Considered	07/07/2009

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